

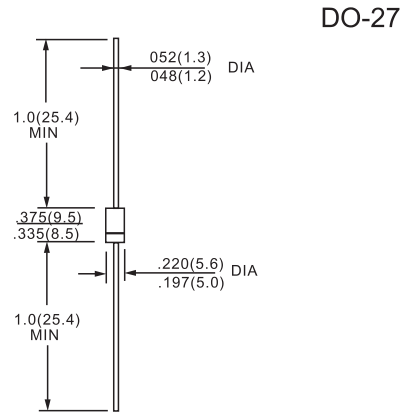


Features

- Diffused Junction
- Low Forward Voltage Drop
- High Current Capability
- High Reliability
- High Surge Current Capability

Mechanical Data

- Case: Molded Plastic
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: Cathode Band
- Weight: 1.2 grams (approx.)
- Mounting Position: Any
- Marking: Type Number



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.
Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

Characteristic	SYMBOLS	SF51	SF52	SF53	SF54	SF55	SF56	SF58	UNITS
Maximum repetitive peak reverse voltage	V_{RRM}	50	100	150	200	300	400	600	V
Maximum RMS voltage	V_{RMS}	35	70	105	140	210	280	420	V
Maximum DC blocking voltage	V_{DC}	50	100	150	200	300	400	600	V
Maximum average forward rectified current 0.375" (9.5mm) lead length at $T_A=55^\circ C$	$I_{(AV)}$	5.0							A
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I_{FSM}	150.0							A
Maximum instantaneous forward voltage at 5.0A	V_F	0.95			1.25			V	
Maximum DC reverse current $T_A=25^\circ C$ at rated DC blocking voltage $T_A=100^\circ C$	I_R	10.0			50.0			μA	
Maximum reverse recovery time (NOTE 1)	t_{rr}	35			ns				
Typical junction capacitance (NOTE 2)	C_J	100.0			50.0			pF	
Typical thermal resistance (NOTE 3)	$R_{\theta JA}$	30.0			$^\circ C/W$				
Operating junction and storage temperature range	T_J, T_{STG}	-65 to +150							$^\circ C$

Note: 1. Reverse recovery condition $I_F=0.5A, I_R=1.0A, I_{rr}=0.25A$
 2. Measured at 1MHz and applied reverse voltage of 4.0V D.C.
 3. Thermal resistance from junction to ambient at 0.375" (9.5mm) lead length, P.C.B. mounted

